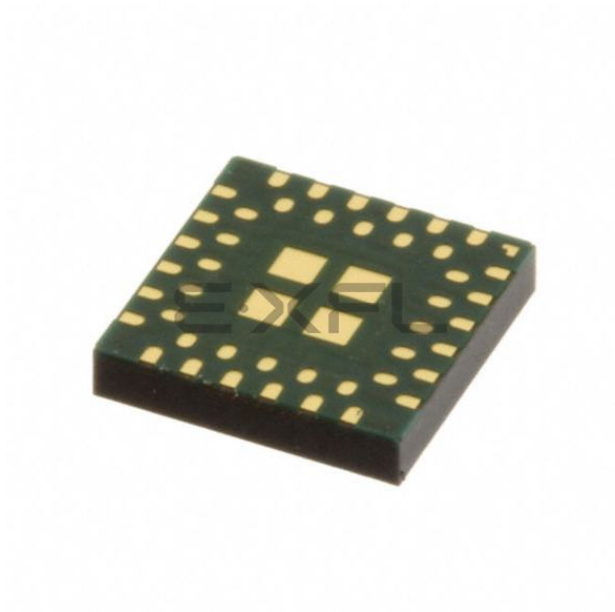

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	I²C, SPI, UART/USART
Peripherals	DMA, WDT
Number of I/O	20
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 5x16b, 4x24b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-VFLGA Exposed Pad
Supplier Device Package	44-MAPLGA (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mkm14z128achh5

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	0.9	1.1	V

3.2 Definition: Operating behavior

Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

3.2.1 Example

This is an example of an operating behavior:

Symbol	Description	Min.	Max.	Unit
I_{WP}	Digital I/O weak pullup/ pulldown current	10	130	µA

3.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

3.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

3.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

4.4 Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
V_{DD}	Digital supply voltage	–0.3	3.6	V
V_{DIO}	Digital input voltage (except $\overline{RESET}$, EXTAL, and XTAL)	–0.3	V_{DD} + 0.3	V
$V_{DTamper}$	Tamper input voltage	–0.3	V_{BAT} + 0.3	V
V_{AIO}	Analog[1], $\overline{RESET}$, EXTAL, and XTAL input voltage	–0.3	V_{DD} + 0.3	V
I_D	Instantaneous maximum current single pin limit (applies to all port pins)	–25	25	mA
V_{DDA}	Analog supply voltage	V_{DD} – 0.3	V_{DD} + 0.3	V
V_{BAT}	RTC battery supply voltage	–0.3	3.6	V

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

5 General

5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

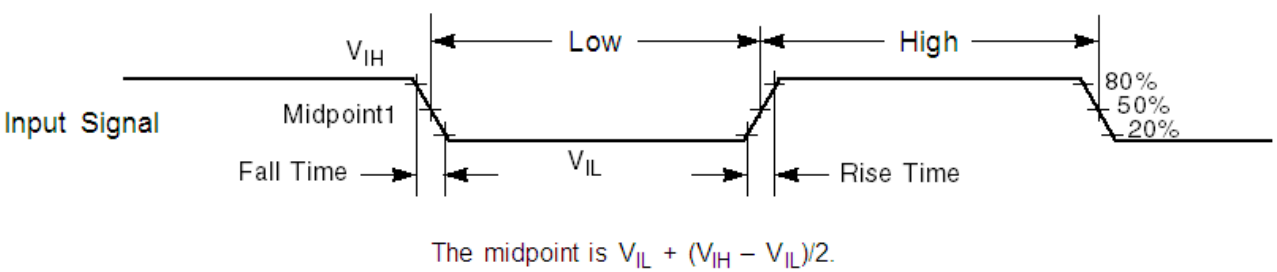

Figure 1. Input signal measurement reference

5.2 Nonswitching electrical specifications

5.2.1 Voltage and current operating requirements

Table 1. Voltage and current operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DD}	Supply voltage when AFE is operational	2.7	3.6	V	
	Supply voltage when AFE is NOT operational	1.71	3.6	V	
V_{DDA}	Analog supply voltage	2.7	3.6	V	
$V_{DD} – V_{DDA}$	V_{DD}-to-V_{DDA} differential voltage	–0.1	0.1	V	
$V_{SS} – V_{SSA}$	V_{SS}-to-V_{SSA} differential voltage	–0.1	0.1	V	
V_{BAT}	RTC battery supply voltage	1.71	3.6	V	1
V_{IH}	Input high voltage • 2.7 V ≤ V_{DD} ≤ 3.6 V • 1.7 V ≤ V_{DD} ≤ 2.7 V	 0.7 × V_{DD} 0.75 × V_{DD}	 — —	 V V	
V_{IL}	Input low voltage • 2.7 V ≤ V_{DD} ≤ 3.6 V • 1.7 V ≤ V_{DD} ≤ 2.7 V	 — —	 0.35 × V_{DD} 0.3 × V_{DD}	 V V	
V_{HYS}	Input hysteresis	0.06 × V_{DD}	—	V	
I_{ICDIO}	Digital pin negative DC injection current — single pin • V_{IN} < V_{SS}-0.3V	-5	—	mA	
I_{ICAIO}	Analog[2], EXTAL, and XTAL pin DC injection current — single pin • V_{IN} < V_{SS}-0.3V (Negative current injection) • V_{IN} > V_{DD}+0.3V (Positive current injection)	 -3 —	 — +3	mA	
I_{ICcont}	Contiguous pin DC injection current —regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins • Negative current injection • Positive current injection	 -25 —	 — +25	mA	
V_{RFVBAT}	V_{BAT} voltage required to retain the VBAT register file	V_{POR_VBAT}	—	V	

1. V_{BAT} always needs to be there for the chip to be operational.
2. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

5.2.2 LVD and POR operating requirements

Table 2. V_{DD} supply LVD and POR operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{POR}	Falling VDD POR detect voltage	0.8	1.1	1.5	V	
V_{LVDH}	Falling low-voltage detect threshold — high range (LVDV=01)	2.48	2.56	2.64	V	

Table continues on the next page...

Table 6. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes

I_{DD_VBAT}	Average current when VDD is OFF and LFSR and Tamper clocks set to 2 Hz.
	• @ 3.0 V
	  • 25 °C
	  • -40 °C
	  • 105 °C
		—	1.3 [7]	3
				2.5
				16
					µA
					µA
					µA
						8, 9

1. See AFE specification for IDDA.
2. 50 MHz core and system clock, 25 MHz bus clock, and 25 MHz flash clock. MCG configured for FBE mode. All peripheral clocks disabled.
3. Should be reduced by 500 µA.
4. 2 MHz core, system, bus clock, and 1 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled. Code executing while (1) loop from flash.
5. 2 MHz core, system and bus clock, and 1MHz flash clock. MCG configured for BLPE mode. All peripheral clocks enabled but peripherals are not in active operation. Code executing while (1) loop from flash.
6. 2 MHz core, system and bus clock, and 1 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled. No flash accesses; some activity on DMA & RAM assumed.
7. Current consumption will vary with number of CPU accesses done and is dependent on the frequency of the accesses and frequency of bus clock. Number of CPU accesses should be optimized to get optimal current value.
8. Includes 32 kHz oscillator current and RTC operation.
9. An external power switch for VBAT should be present on board to have better battery life and keep VBAT pin powered in all conditions. There is no internal power switch in RTC.

5.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V_{RE1}	Radiated emissions voltage, band 1	0.15–50	14	dBµV	1, 2
V_{RE2}	Radiated emissions voltage, band 2	50–150	16	dBµV	
V_{RE3}	Radiated emissions voltage, band 3	150–500	12	dBµV	
V_{RE4}	Radiated emissions voltage, band 4	500–1000	5	dBµV	
V_{RE_IEC}	IEC level	0.15–1000	M	—	2, 3

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. V_{DD} = 3.3 V, T_A = 25 °C, f_{OSC} = 10 MHz (crystal), f_{SYS} = 50 MHz, f_{BUS} = 25 MHz
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

5.3.2 General switching specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and I^2C signals.

Table 10. General switching specifications

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Asynchronous path	16	—	ns	2
	External reset pulse width (digital glitch filter disabled)	100	—	ns	2
	Port rise and fall time—Low (All pins) and high drive (only PTC2) strength				3
	• Slew disabled				
	• $1.71 \le V_{DD} \le 2.7$ V	—	8	ns	
	• $2.7 \le V_{DD} \le 3.6$ V	—	5	ns	
	• Slew enabled				
	• $1.71 \le V_{DD} \le 2.7$ V	—	27	ns	
	• $2.7 \le V_{DD} \le 3.6$ V	—	16	ns	

1. The greater synchronous and asynchronous timing must be met.
2. This is the shortest pulse that is guaranteed to be recognized.
3. Only PTC2 has high drive capability and load is 75 pF, other pins load (low drive) is 25 pF.

5.4 Thermal specifications

5.4.1 Thermal operating requirements

Table 11. Thermal operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
T_J	Die junction temperature	–40	105	°C	
T_A	Ambient temperature	–40	85	°C	1

1. Maximum T_A can be exceeded only if the user ensures that T_J does not exceed the maximum. The simplest method to determine T_J is: $T_J = T_A + \theta_{JA} \times$ chip power dissipation

Table 18. MCG specifications (continued)

Symbol	Description		Min.	Typ.	Max.	Unit	Notes
Δf_{ints_t}	Total deviation of internal reference frequency (slow clock) over voltage and temperature		—	+0.5/-0.7	—	%	
Δf_{ints_t}	Total deviation of internal reference frequency (slow clock) over fixed voltage and full operating temperature range		-2	—	+2	%	
f_{ints_t}	Internal reference frequency (slow clock) — user trimmed		31.25	—	39.0625	kHz	
$\Delta_{fdco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM		—	± 0.3	± 0.6	$\%f_{dco}$	1
Δf_{dco_t}	Total deviation of trimmed average DCO output frequency over voltage and temperature		—	+0.5/-0.7		$\%f_{dco}$	1
Δf_{dco_t}	Total deviation of trimmed average DCO output frequency over fixed voltage and temperature range of 0–70°C		—	± 0.4	—	$\%f_{dco}$	1
f_{intf_ft}	Internal reference frequency (fast clock) — factory trimmed at nominal VDD and 25°C		—	4	—	MHz	
Δf_{intf_t}	Total deviation of internal reference frequency (fast clock) over voltage and temperature — factory trimmed at nominal VDD and 25°C		—	+1/-2	—	%	
f_{intf_t}	Internal reference frequency (fast clock) — user trimmed at nominal VDD and 25 °C		3	—	5	MHz	
f_{loc_low}	Loss of external clock minimum frequency — RANGE = 00		(3/5) x f_{ints_t}	—	—	kHz	
f_{loc_high}	Loss of external clock minimum frequency — RANGE = 01, 10, or 11		(16/5) x f_{ints_t}	—	—	kHz	
FLL							
f_{dco}	DCO output frequency range	Low-range (DRS=00) 640 × f_{ints_t}	20	20.97	22	MHz	2, 3
		Mid-range (DRS=01) 1280 × f_{ints_t}	40	41.94	45	MHz	
		Mid-high range (DRS=10) 1920 × f_{ints_t}	60	62.91	67	MHz	
		High-range (DRS=11) 2560 × f_{ints_t}	80	83.89	90	MHz	

Table continues on the next page...

Table 18. MCG specifications (continued)

Symbol	Description		Min.	Typ.	Max.	Unit	Notes
$f_{dco\_t\_DMX32}$	DCO output frequency	Low-range (DRS=00) $732 \times f_{ints\_t}$	—	23.99	—	MHz	4, 5, 6
		Mid-range (DRS=01) $1464 \times f_{ints\_t}$	—	47.97	—	MHz	
		Mid-high range (DRS=10) $2197 \times f_{ints\_t}$	—	71.99	—	MHz	
		High-range (DRS=11) $2929 \times f_{ints\_t}$	—	95.98	—	MHz	
J_{cyc_fll}	FLL period jitter		—	70	140	ps	7
$t_{fll\_acquire}$	FLL target frequency acquisition time		—	—	1	ms	8
PLL							
f_{vco}	VCO operating frequency		11.71875	12.288	14.6484375	MHz	
I_{pll}	PLL operating current • IO 3.3 V current • Max core voltage current		—	300 100	—	µA	9
f_{pll_ref}	PLL reference frequency range		31.25	32.768	39.0625	kHz	
J_{cyc_pll}	PLL period jitter (RMS) • f_{vco} = 12 MHz				700	ps	10
D_{lock}	Lock entry frequency tolerance		± 1.49	—	± 2.98	%	11
D_{unl}	Lock exit frequency tolerance		± 4.47	—	± 5.97	%	
t_{pll_lock}	Lock detector detection time		—	—	$150 \times 10^{-6} + 1075(1/f_{pll\_ref})$	s	12

1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
2. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=0.
3. Chip max freq is 5075 MHz, so Mid-range with DRS = 10 and High-range of DCO cannot be used and should not be configured.
4. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=1.
5. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
6. Chip max freq is 5075 MHz, so Mid-range with DRS = 10 and High-range of DCO cannot be used and should not be configured.
7. This specification is based on standard deviation (RMS) of period or frequency.
8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
9. Excludes any oscillator currents that are also consuming power while PLL is in operation.
10. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
11. Will be updated later
12. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

6.2.2.2 Oscillator frequency specifications

Table 20. Oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{osc_lo}	Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00)	32	—	40	kHz	
$f_{osc\_hi\_1}$	Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01)	1	—	8	MHz	
$f_{osc\_hi\_2}$	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	—	32	MHz	
f_{ec_extal}	Input clock frequency (external clock mode)	—	—	48	MHz	1, 2
t_{dc_extal}	Input clock duty cycle (external clock mode)	40	50	60	%	
t_{cst}	Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)	—		—	ms	3, 4
	Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)	—		—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)	—	0.6	—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)	—	1	—	ms	

1. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.
2. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.
3. Proper PC board layout procedures must be followed to achieve specifications.
4. Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S register being set.

6.2.3 32 kHz oscillator electrical characteristics

6.2.3.1 32 kHz oscillator DC electrical specifications

Table 21. 32kHz oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V_{BAT}	Supply voltage	1.71	—	3.6	V
R_F	Internal feedback resistor	—	100	—	MΩ
C_{para}	Parasitical capacitance of EXTAL32 and XTAL32	—	5	7	pF
V_{pp}[1]	Peak-to-peak amplitude of oscillation	—	0.6	—	V

1. When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

6.4.1 ADC electrical specifications

All ADC channels meet the 12-bit single-ended accuracy specifications.

6.4.1.1 16-bit ADC operating conditions

Table 27. 16-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ.[1]	Max.	Unit	Notes
V_{DDA}	Supply voltage	Absolute	1.71	—	3.6	V	—
ΔV_{DDA}	Supply voltage	Delta to V_{DD} ($V_{DD} - V_{DDA}$)	-100	0	+100	mV	2
ΔV_{SSA}	Ground voltage	Delta to V_{SS} ($V_{SS} - V_{SSA}$)	-100	0	+100	mV	2
V_{REFH}	ADC reference voltage high		1.13	V_{DDA}	V_{DDA}	V	
V_{REFL}	ADC reference voltage low		V_{SSA}	V_{SSA}	V_{SSA}	V	
V_{ADIN}	Input voltage		V_{REFL}	—	V_{REFH}	V	—
C_{ADIN}	Input capacitance	• 16-bit mode • 8-bit / 10-bit / 12-bit modes	— —	8 4	10 5	pF	—
R_{ADIN}	Input series resistance		—	2	5	kΩ	—
R_{AS}	Analog source resistance (external)	12-bit modes f_{ADCK} < 4 MHz	—	—	5	kΩ	3
f_{ADCK}	ADC conversion clock frequency	≤ 12-bit mode	1.0	—	18.0	MHz	4
f_{ADCK}	ADC conversion clock frequency	16-bit mode	2.0	—	12.0	MHz	4
C_{rate}	ADC conversion rate	≤ 12-bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	20.000	—	818.330	Ksps	5
C_{rate}	ADC conversion rate	16-bit mode No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	37.037	—	461.467	Ksps	5

1. Typical values assume V_{DDA} = 3.0 V, Temp = 25 °C, f_{ADCK} = 1.0 MHz, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8 Ω analog source resistance. The R_{AS}/C_{AS} time constant should be kept to < 1 ns.
4. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
5. For guidelines and examples of conversion rate calculation, download the ADC calculator tool.

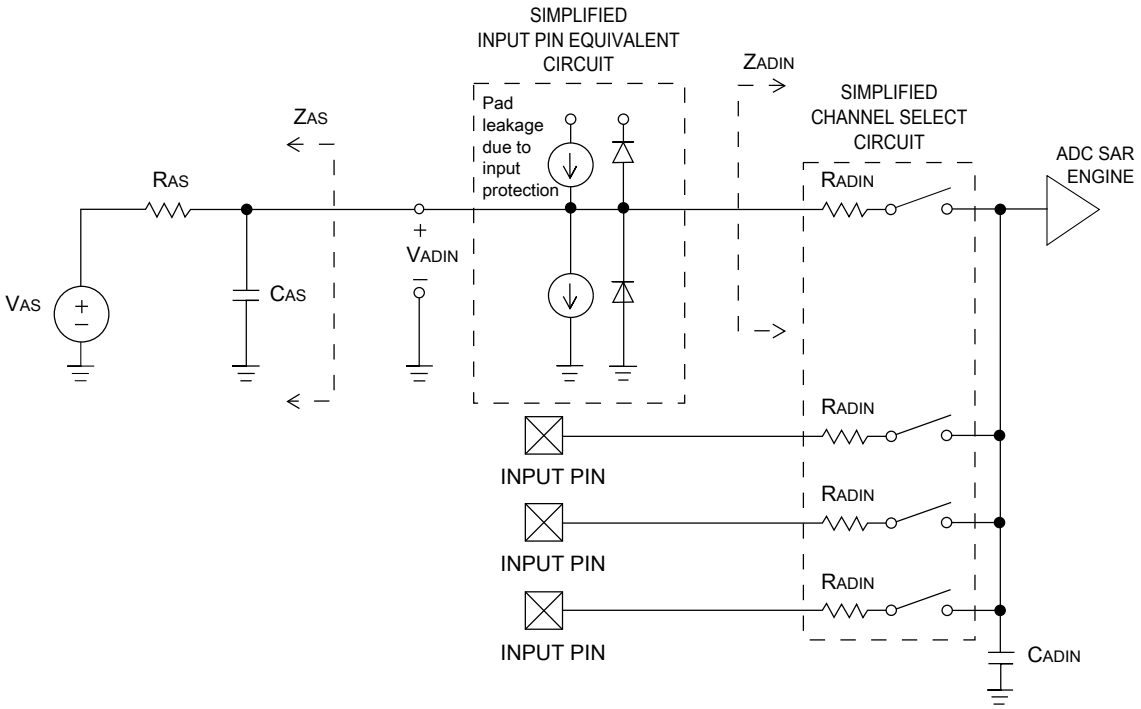

Figure 2. ADC input impedance equivalency diagram

6.4.1.2 16-bit ADC electrical characteristics

Table 28. 16-bit ADC characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA})

Symbol	Description	Conditions[1]	Min.	Typ.[2]	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0	1.2	2.4	3.9	MHz	t_{ADACK} = 1/ f_{ADACK}
		• ADLPC = 1, ADHSC = 1	2.4	4.0	6.1	MHz	
		• ADLPC = 0, ADHSC = 0	3.0	5.2	7.3	MHz	
		• ADLPC = 0, ADHSC = 1	4.4	6.2	9.5	MHz	
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes	—	±4	±6.8	LSB[4]	5
		• <12-bit modes	—	±1.4	±2.1		
DNL	Differential non-linearity	• 12-bit modes	—	±0.7	–1.1 to +1.9	LSB[4]	5
		• <12-bit modes	—	±0.2	–0.3 to 0.5		
INL	Integral non-linearity	• 12-bit modes	—	±1.0	–2.7 to +1.9	LSB[4]	5
		• <12-bit modes	—	±0.5	–0.7 to +0.5		

Table continues on the next page...

Table 35. ΣΔ ADC standalone specifications (continued)

Symbol	Description	Conditions	Min	Typ[1]	Max	Unit	Notes
VIN_{diff}	Input range	Differential		+/- 500		mV	
		Single Ended		+/- 250		mV	
SNR	Signal to Noise Ratio	Normal Mode • f_{IN}=50Hz; common mode=0V, V_{pp}= 500mV (differential ended) • f_{IN}=50Hz; common mode=0V, V_{pp}= 500mV (full range se.) Low-Power Mode • f_{IN}=50Hz; common mode=0V, V_{pp}=500mV (diff.) • f_{IN}=50Hz; common mode=0V, V_{pp}=500mV (full range se.)	88 76	90 78		dB	
$\Delta Gain_{Temp}$	Gain Temperate Drift - Gain error caused by temperature drifts [2]	• Gain bypassed Vpp = 500 mV (differential) • PGA bypassed Vpp = 500 mV (differential), VCM = 0 V			55	ppm/°C	
ΔOffset Temp	Offset Temperate Drift - Offset error caused by temperature drifts [3]	• Gain bypassed Vpp = 500 mV (differential), VCM = 0 V			30	ppm/°C	
SINAD	Signal-to-Noise + Distortion Ratio	Normal Mode • f_{IN}=50Hz; common mode=0V, V_{pp}= 500mV (diff.) • f_{IN}=50Hz; common mode=0V, V_{pp}= 500mV (full range se.) Low-Power Mode • f_{IN}=50Hz; common mode=0V, V_{pp}=500mV (diff.) • f_{IN}=50Hz; common mode=0V, V_{pp}=500mV (full range se.)		80 74		dB	
CMMR	Common Mode Rejection Ratio	• f_{IN}=50Hz; common mode=0V, V_{id}=100 mV		90		dB	
$PSRR_{AC}$	AC Power Supply Rejection Ratio	Gain=01, VCC = 3V ± 100mV, f_{IN} = 50 Hz		60		dB	
XT	Crosstalk	Gain=01, V_{id} = 500 mV, f_{IN} = 50 Hz			-100	dB	
f_{MCLK}	Modulator Clock Frequency Range	Normal Mode Low-Power Mode	0.03 0.03		6.5 1.6	MHz	
I_{DDA_ADC}	Current Consumption by ADC (each channel)	Normal Mode (f_{MCLK} = 6.144 MHz, OSR= 2048) Low-Power Mode (f_{MCLK} = 0.768MHz, OSR= 256)			1.4 0.5	mA	
R_{as}	Equivalent input impedance at normal operating mode (6.144 MHz)	PGA disabled		73		kΩ	

1. Typical values assume VDDA = 3.0 V, Temp = 25°C, f_{MCLK} = 6.144 MHz, OSR = 2048 for Normal mode and f_{MCLK} = 768 kHz, OSR = 256 for Low-Power Mode unless otherwise stated. Typical values are for reference only and are not tested in production.
2. Represent combined gain temperature drift of the SD ADC, and Internal 1.2 VREF blocks.
3. Represent combined offset temperature drift of the SD ADC, and Internal 1.2 VREF blocks; Defined by shorting both differential inputs to ground.

6.4.4.3 External modulator interface

The external modulator interface on this device comprises of a Clock signal and 1-bit data signal. Depending on the modulator device being used the interface works as follows:

- Clock supplied to external modulator which drives data on rising edge and the KM device captures it on falling edge or next rising edge.
- Clock and data are supplied by external modulator and KM device can sample it on falling edge or next rising edge.

Depending on control bit in AFE, the sampling edge is changed.

6.5 Timers

See General switching specifications.

6.6 Communication interfaces

6.6.1 I2C switching specifications

See General switching specifications.

6.6.2 UART switching specifications

See General switching specifications.

6.6.3 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following table provides some reference values to be met on SoC.

Table 36. SPI switching characteristics at 2.7 V (2.7 - 3.6)

Description	Min.	Max.	Unit	Notes
Frequency of operation (F_{sys})	—	50	MHz	1
SCK frequency • Master • Slave	2	12.5 12.5	MHz Mhz	3
SCK Duty Cycle	50%	—	—	
Data Setup Time (inputs, tSUI) • Master • Slave	25 3		ns	
Input Data Hold Time (inputs, tHI) • Master • Slave	0 1		ns	
Data hold time (outputs, tHO) • Master • Slave	0 0		ns	
Data Valid Out Time (after SCK edge, tDVO) • Master • Slave	13 28		ns	
Rise time input • Master • Slave	1 1		ns	
Fall time input • Master • Slave	1 1		ns	
Rise time output • Master • Slave	8.9 8.9		ns	
Fall time output • Master • Slave	7.8 7.8		ns	

1. SPI modules will work on core clock.
2. F_{sys}/(Max Divider Value from registers)
3. F_{SYS}/2 in Master mode and F_{SYS}/4 in Slave mode. F_{SYS}/4 in Master as well as Slave Modes, where F_{SYS}=50Mhz

NOTE

The values assumed for input transition and output load are:
Input transition = 1 ns Output load = 50 pF

Table 37. SPI switching characteristics at 1.7 V (1.7 - 3.6)

Description	Min.	Max.	Unit	Notes
Frequency of operation (F_{sys})	—	50	MHz	

Table continues on the next page...

Table 37. SPI switching characteristics at 1.7 V (1.7 - 3.6) (continued)

Description	Min.	Max.	Unit	Notes
SCK frequency • Master • Slave		9 9	MHz Mhz	
SCK Duty Cycle	50%	—	—	
Data Setup Time (inputs, tSUI) • Master • Slave	42 3.5		ns	
Input Data Hold Time (inputs, tHI) • Master • Slave	0 1		ns	
Data hold time (outputs, tHO) • Master • Slave	-3 0		ns	
Data Valid Out Time (tDVO) • Master • Slave	16 44		ns	1
Rise time input • Master • Slave	1 1		ns	
Fall time input • Master • Slave	1 1		ns	
Rise time output • Master • Slave	14.4 14.4		ns	
Fall time output • Master • Slave	12.4 12.4		ns	

1. SCK frequency of 9 Mhz is applicable only in the case that the input setup time of the device outside is not more than 11.5 ns, else the frequency would need to be lowered.

The following table represents SPI Switching specification in OD cells

Table 38. SPI switching characteristics at 1.7 V (1.7 - 3.6)

Description	Min.	Max.	Unit	Notes
Data Setup Time (inputs, tSUI) • Master • Slave	51 4		ns	
Input Data Hold Time (inputs, tHI) • Master • Slave	0 1		ns	
Data hold time (outputs, tHO) • Master • Slave	-15 0		ns	
Data Valid Out Time (tDVO) • Master • Slave	61 93		ns	

Table continues on the next page...

Table 38. SPI switching characteristics at 1.7 V (1.7 - 3.6) (continued)

Description	Min.	Max.	Unit	Notes
Rise time input • Master • Slave	 1 1		ns	
Fall time input • Master • Slave	 1 1		ns	
Rise time output • Master • Slave	 30.4 30.4		ns	
Fall time output • Master • Slave	 33.5 29.0		ns	

Table 39. SPI switching characteristics at 2.7 V (2.7 - 3.6)

Description	Min.	Max.	Unit	Notes
Data Setup Time (inputs, tSUI) • Master • Slave	 29 4		ns	
Input Data Hold Time (inputs, tHI) • Master • Slave	 0 1		ns	
Data hold time (outputs, tHO) • Master • Slave	 0 0		ns	
Data Valid Out Time (after SCK edge, tDVO) • Master • Slave	 49 49		ns	
Rise time input • Master • Slave	 1 1		ns	
Fall time input • Master • Slave	 1 1		ns	
Rise time output • Master • Slave	 17.3 17.3		ns	
Fall time output • Master • Slave	 16.6 16.0		ns	

6.7 Human-Machine Interfaces (HMI)

6.7.1 LCD electrical characteristics

Table 40. LCD electricals

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{Frame}	LCD frame frequency	28	30	58	Hz	
C_{LCD}	LCD charge pump capacitance — nominal value	—	100	—	nF	1
C_{BYLCD}	LCD bypass capacitance — nominal value	—	100	—	nF	1
C_{Glass}	LCD glass capacitance	—	2000	8000	pF	2
V_{IREG}	V_{IREG}					3
	• HREFSEL=0, RVTRIM=1111	—	1.11	—	V	
	• HREFSEL=0, RVTRIM=1000	—	1.01	—	V	
	• HREFSEL=0, RVTRIM=0000	—	0.91	—	V	
Δ_{RTRIM}	V_{IREG} TRIM resolution	—	—	3.0	% V_{IREG}	
I_{VIREG}	V_{IREG} current adder — RVEN = 1	—	1	—	µA	4
I_{RBIAS}	RBIAS current adder	—	15	—	µA	
	• LADJ = 10 or 11 — High load (LCD glass capacitance ≤ 8000 pF)	—	3	—	µA	
	• LADJ = 00 or 01 — Low load (LCD glass capacitance ≤ 2000 pF)					
VLL2	VLL2 voltage					
	• HREFSEL = 0	2.0 – 5%	2.0	—	V	
VLL3	VLL3 voltage	3.0 – 5%	3.0	—	V	

1. The actual value used could vary with tolerance.
2. For highest glass capacitance values, LCD_GCR[LADJ] should be configured as specified in the LCD Controller chapter within the device's reference manual.
3. V_{IREG} maximum should never be externally driven to any level other than V_{DD} - 0.15 V.
4. 2000 pF load LCD, 32 Hz frame frequency.

NOTE

KM family devices have a 1/3 bias controller that works with a 1/3 bias LCD glass. To avoid ghosting, the LCD OFF threshold should be greater than VLL1 level. If the LCD glass has an OFF threshold less than VLL1 level, use the internal VREG mode and generate VLL1 internally using RVTRIM option. This can reduce VLL1 level to allow for a lower OFF threshold LCD glass.

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to freescale.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
44-pin LGA	98ASA00239D
64-pin LQFP	98ASS23234W
100-pin LQFP	98ASS23308W

8 Pinout

NOTE

VSS also connects to flag on 44 LGA.

8.1 Package Types

KM family of devices shall support the following packages options:

- 100-pin LQFP (14 x 14 mm^2)
- 64-pin LQFP (10 x 10 mm^2)
- 44-pin LGA (5 x 5 mm^2)

NOTE

Pin muxing selection between TAMPER0 and WKUP is done using control bit in RTC registers.

NOTE

All pin muxing configurations reset to default value on any reset assertion (reset asserts on VLLSx mode exit).

When RESET pin is used as GPIO and pulled low; an internal reset (e.g. VLLSx mode exit or WDOG reset, etc) will make this pin function as RESET (default function) and since it is pulled low, it will appear as if pin reset is asserted and will cause full chip reset.

NOTE

- For devices other than MKMx4, the SDADP3 and SDADM3 functions on the corresponding pins are disabled.
- All input pins including TAMPER pins must be pulled up or down to avoid extra power consumption.

8.2 KM Signal Multiplexing and Pin Assignments

100 QFP	64 QFP	44 LGA	DEFAULT	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
1	1	—	Disabled	LCD23	PTA0						
2	2	—	Disabled	LCD24	PTA1						
3	3	—	Disabled	LCD25	PTA2						
4	—	—	Disabled	LCD26	PTA3						
5	4	1	NMI_B	LCD27	PTA4	LLWU_P15					NMI_B
6	5	2	Disabled	LCD28	PTA5	CMP0OUT					
7	6	3	Disabled	LCD29	PTA6	PXBAR_IN0	LLWU_P14				
8	7	4	Disabled	LCD30	PTA7	PXBAR_OUT0					
9	—	—	Disabled	LCD31	PTB0						
10	8	5	VDD	VDD							
11	9	6	VSS	VSS							
12	—	—	Disabled	LCD32	PTB1						
13	—	—	Disabled	LCD33	PTB2						
14	—	—	Disabled	LCD34	PTB3						
15	—	—	Disabled	LCD35	PTB4						
16	—	—	Disabled	LCD36	PTB5						
17	—	—	Disabled	LCD37/ CMP1P0	PTB6						
18	10	—	Disabled	LCD38	PTB7	AFE_CLK					
19	11	—	Disabled	LCD39	PTC0	SCI3_RTS	PXBAR_IN1				
20	12	—	Disabled	LCD40/ CMP1P1	PTC1	SCI3_CTS					
21	13	—	Disabled	LCD41	PTC2	SCI3_TxD	PXBAR_OUT1				
22	14	—	Disabled	LCD42/ CMP0P3	PTC3	SCI3_RxD	LLWU_P13				
23	—	—	Disabled	LCD43	PTC4						
24	15	7	VBAT	VBAT							
25	16	8	XTAL32K	XTAL32K							
26	17	9	EXTAL32K	EXTAL32K							
27	18	10	VSS	VSS							
28	18	10	TAMPER2	TAMPER2							
29	18	10	TAMPER1	TAMPER1							
30	19	11	WKUP	TAMPER0							

8.3.1 100-pin LQFP

Figure below shows the KM 100 LQFP pinouts.

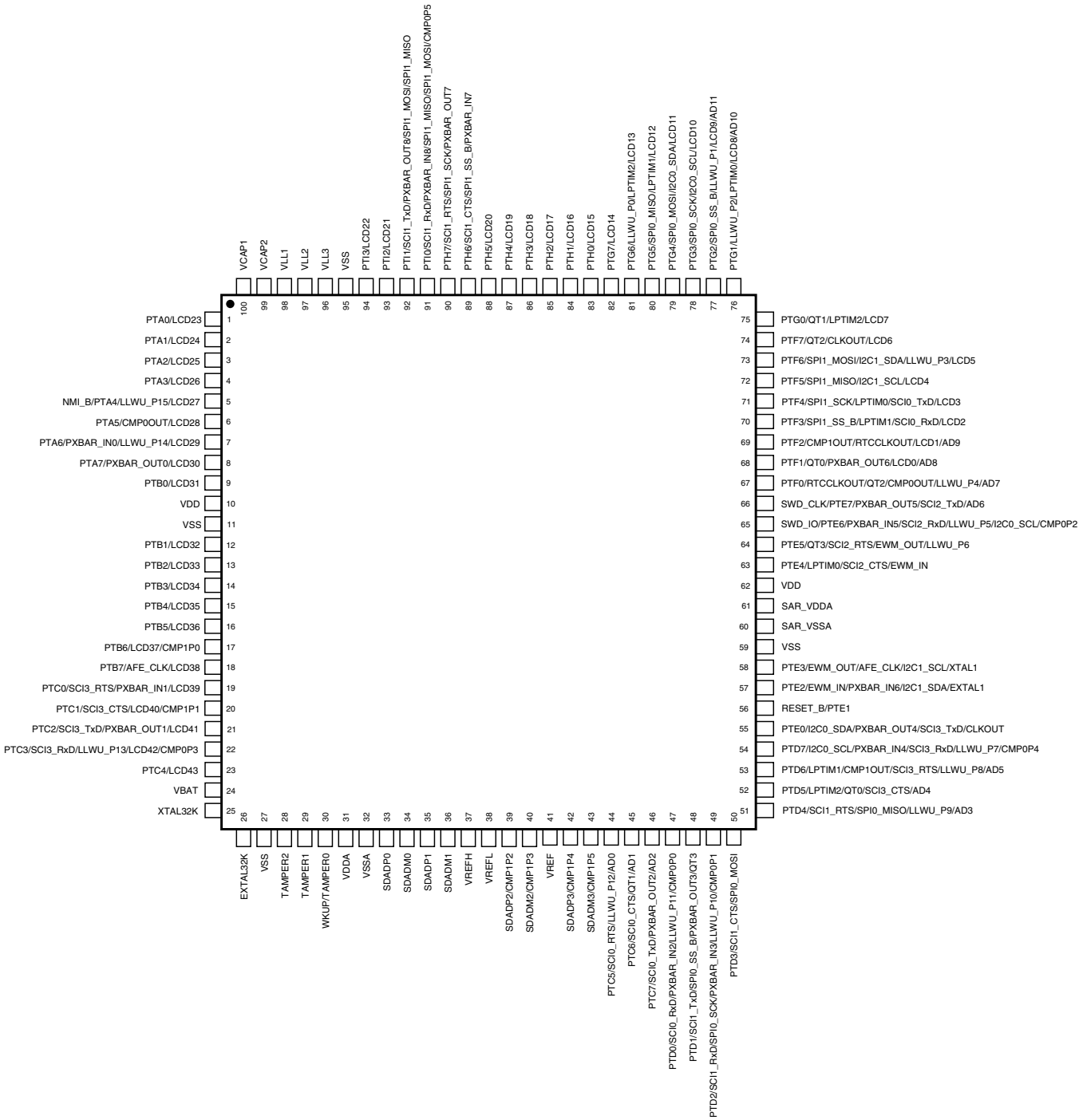

Figure 6. 100-pin LQFP Pinout Diagram

8.3.2 64-pin LQFP

Figure below shows the 64-pin LQFP pinouts.

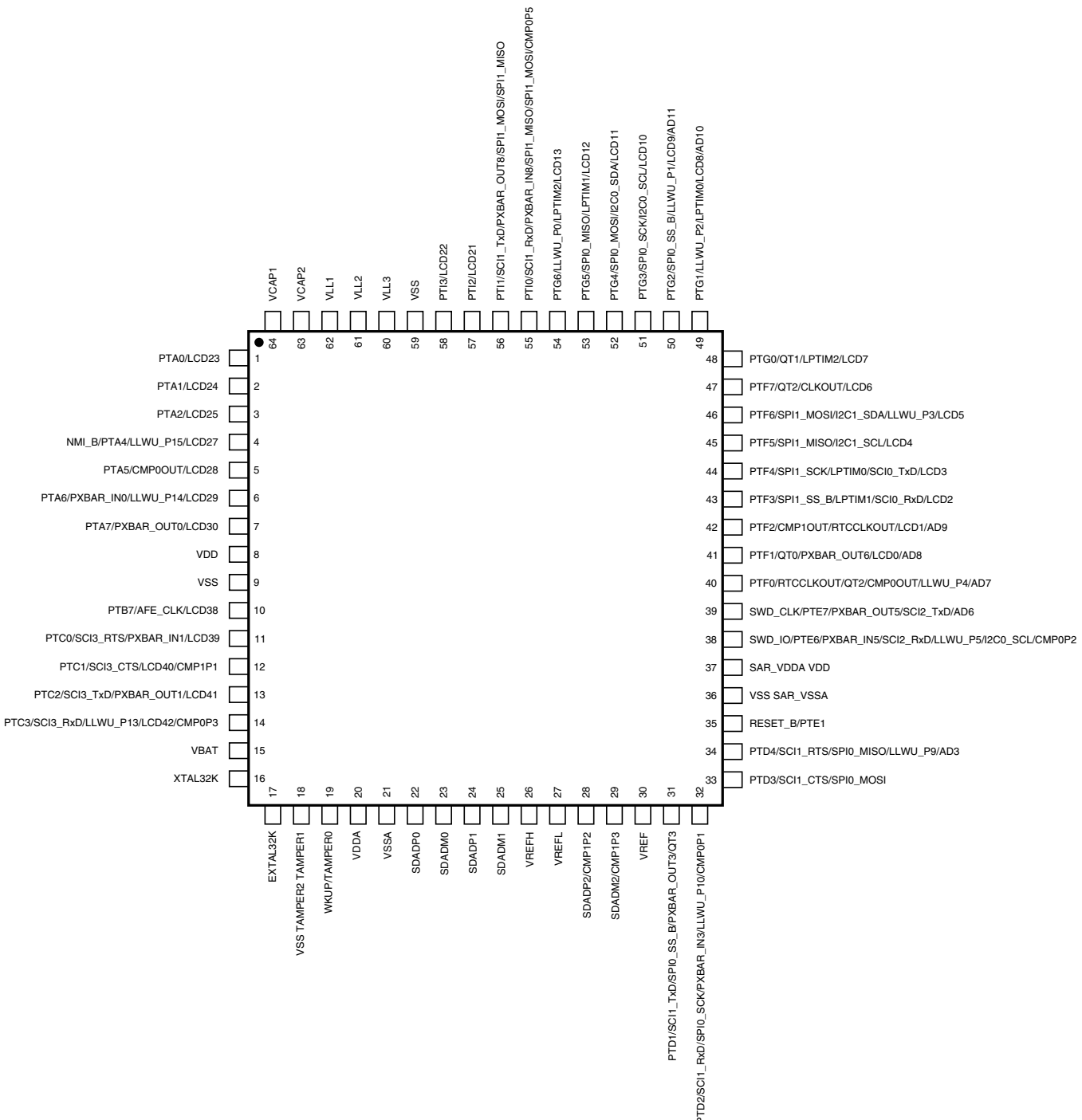

Figure 7. 64-pin LQFP Pinout Diagram